AUTOMOTIVE GRADE



Vishay Semiconductors

High Speed Infrared Emitting Diode, 890 nm, **Surface Emitter Technology**



FEATURES

· Package type: surface-mount

• Package form: PLCC-2

Dimensions (L x W x H in mm): 3.5 x 2.8 x 1.75

AEC-Q101 qualified

Peak wavelength: λ_p = 890 nm

High reliability

· High radiant intensity

• Angle of half intensity: $\varphi = \pm 60^{\circ}$

• Suitable for high pulse current operation

• Floor life: 168 h, MSL 3, according to J-STD-020

· Lead (Pb)-free reflow soldering

· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

HALOGEN FREE **GREEN**

DESCRIPTION

As part of the SurfLight M portfolio, the VSMY3890X01 is an infrared, 890 nm emitting diode based on surface emitter technology with high radiant intensity, high optical power and high speed, molded in a PLCC-2 package for surface mounting (SMD).

RELEASED FOR APPLICATIONS

- Infrared radiation source for operation with CMOS cameras (illumination)
- · High speed IR data transmission
- · Automotive sensors
- · Light curtain

| PRODUCT SUMMARY | | | | | |
|-----------------|------------------------|--------------|---------------------|---------------------|--|
| COMPONENT | I _e (mW/sr) | φ (°) | λ _P (nm) | t _r (ns) | |
| VSMY3890X01 | 18 | ± 60 | 890 | 15 | |

Note

Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION | | | | | |
|----------------------|---------------|------------------------------|--------------|--|--|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM | | |
| VSMY3890X01-GS08 | Tape and reel | MOQ: 7500 pcs, 1500 pcs/reel | PLCC-2 | | |
| VSMY3890X01-GS18 | Tape and reel | MOQ: 8000 pcs, 8000 pcs/reel | PLCC-2 | | |

Note

· MOQ: minimum order quantity



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| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | |
|--|----------------------------------|-------------------|---------------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | |
| Reverse voltage | | V _R | 5 | V | |
| Forward current | | I _F | 100 | mA | |
| Pulse peak forward current | $t_p/T = 0.5, t_p = 100 \ \mu s$ | I _{FM} | I _{FM} 200 | | |
| Surge forward current | t _p = 100 μs | I _{FSM} | 1 | Α | |
| Power dissipation | | P _V | 190 | mW | |
| Junction temperature | | Tj | 100 | °C | |
| Operating temperature range | | T _{amb} | -40 to +85 | °C | |
| Storage temperature range | | T _{stg} | -40 to +110 | °C | |
| Soldering temperature | According to Fig. 7, J-STD-020 | T _{sd} | 260 | °C | |
| Thermal resistance junction-to-ambient | J-STD-051, soldered on PCB | R _{thJA} | 250 | K/W | |

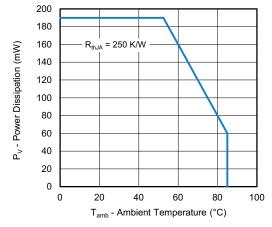


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

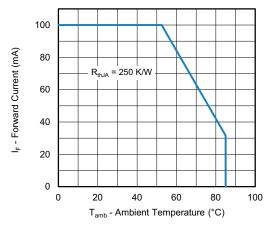


Fig. 2 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|--|---|------------------|------------------------------------|------|------|-------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | V _F | - | 1.6 | 1.9 | V |
| | $I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$ | V _F | - | 2.8 | - | V |
| Temperature coefficient of V _F | I _F = 1 mA | TK _{VF} | - | -2.0 | - | mV/K |
| | I _F = 100 mA | TK _{VF} | - | -2.0 | - | mV/K |
| Reverse current | | I _R | Not designed for reverse operation | | | μA |
| Junction capacitance | V _R = 0 V, f = 1 MHz, E = 0 | Cj | - | 60 | - | pF |
| Podřed Moneck | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | l _e | 12 | 18 | 25 | mW/sr |
| Radiant intensity | $I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$ | le | - | 160 | - | mW/sr |
| Radiant power | $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ | фe | - | 55 | - | mW |
| Temperature coefficient of φ _e | I _F = 100 mA | TKφe | - | -0.2 | - | %/K |
| Angle of half intensity | | φ | - | ± 60 | - | 0 |
| Peak wavelength | I _F = 100 mA | λρ | 875 | 890 | 905 | nm |
| Spectral bandwidth | I _F = 100 mA | Δλ | - | 35 | - | nm |
| Temperature coefficient of λ_p | I _F = 100 mA | TKλ _p | - | 0.3 | - | nm/K |
| Rise time | I _F = 100 mA | t _r | - | 15 | - | ns |
| Fall time | I _F = 100 mA | t _f | - | 15 | - | ns |

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

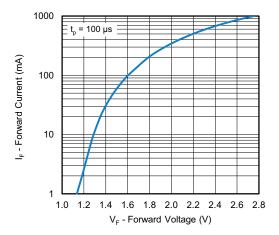


Fig. 3 - Forward Current vs. Forward Voltage

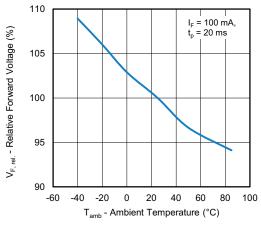


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

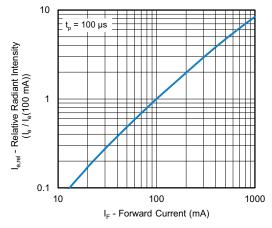


Fig. 5 - Relative Radiant Intensity vs. Forward Current

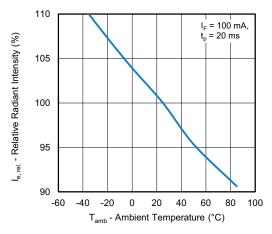


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

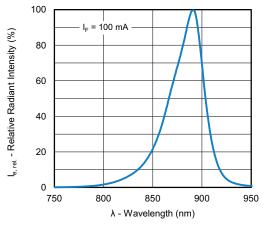


Fig. 7 - Relative Radiant Intensity vs. Wavelength

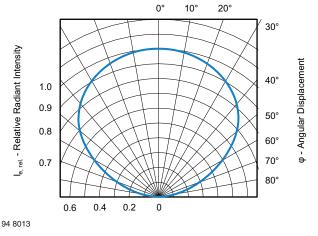
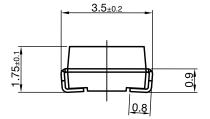
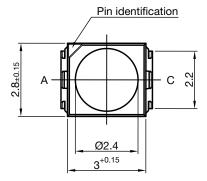


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

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PACKAGE DIMENSIONS in millimeters



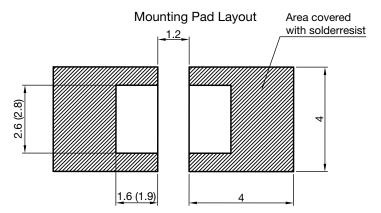




Dimensions in mm

Drawing-No.: 6.541-5067.02-4

Issue: 5; 23.09.13



Dimensions: Reflow and vapor phase (wave soldering)

SOLDER PROFILE

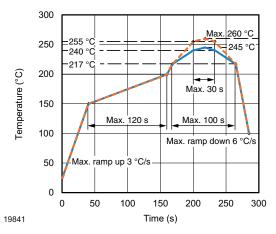


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 3, according to J-STD-020

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ M.



TAPE AND REEL

PLCC-2 components are packed in antistatic blister tape (DIN IEC (CO) 564) for automatic component insertion. Cavities of blister tape are covered with adhesive tape.

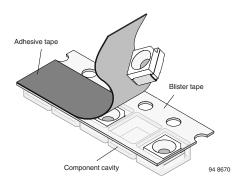


Fig. 10 - Blister Tape

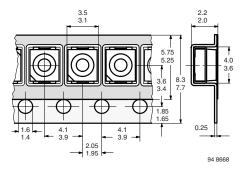


Fig. 11 - Tape Dimensions in mm for PLCC-2

MISSING DEVICES

A maximum of 0.5 % of the total number of components per reel may be missing, exclusively missing components at the beginning and at the end of the reel. A maximum of three consecutive components may be missing, provided this gap is followed by six consecutive components.

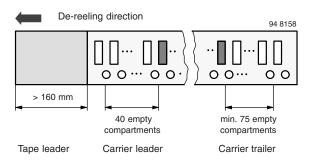


Fig. 12 - Beginning and End of Reel

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The tape leader is at least 160 mm and is followed by a carrier tape leader with at least 40 empty compartments. The tape leader may include the carrier tape as long as the cover tape is not connected to the carrier tape. The least component is followed by a carrier tape trailer with a least 75 empty compartments and sealed with cover tape.

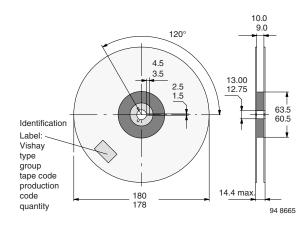


Fig. 13 - Dimensions of Reel-GS08

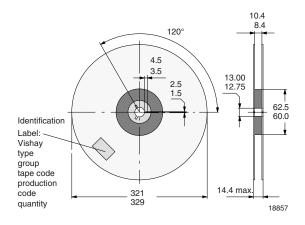


Fig. 14 - Dimensions of Reel-GS18

COVER TAPE REMOVAL FORCE

The removal force lies between 0.1 N and 1.0 N at a removal speed of 5 mm/s. In order to prevent components from popping out of the blisters, the cover tape must be pulled off at an angle of 180° with regard to the feed direction.

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